

TDA7386

4 x 40W FOUR BRIDGE CAR RADIO AMPLIFIER

PRODUCT PREVIEW

- HIGH OUTPUT POWER CAPABILITY: 4 x 40W max./4Ω EIAJ
 4 x 45W max./4Ω @ 14.4V, 1KHz
 4 x 28W/4Ω @ 14.4V, 1KHz, 10%
 4 x 23W/4Ω @ 13.2V, 1KHz, 10%
- LOW DISTORTION
- LOW OUTPUT NOISE
- ST-BY FUNCTION
- MUTE FUNCTION
- AUTOMUTE AT MIN. SUPPLY VOLTAGE DE-TECTION
- LOW EXTERNAL COMPONENT COUNT:
 - INTERNALLY FIXED GAIN (26dB)
 NO EXTERNAL COMPENSATION
 - NO BOOTSTRAP CAPACITORS

PROTECTIONS:

- OUTPUT SHORT CIRCUIT TO GND, TO V_S, ACROSS THE LOAD
- VERY INDUCTIVE LOADS
- OVERRATING CHIP TEMPERATURE WITH SOFT THERMAL LIMITER
- LOAD DUMP VOLTAGE

BLOCK AND APPLICATION DIAGRAM



FLEXIWATT25

ORDERING NUMBER: TDA7386

- FORTUITOUS OPEN GND
- REVERSED BATTERY
- ESD

DESCRIPTION

The TDA7386 is a new technology class AB Audio Power Amplifier in Flexiwatt 25 package designed for high end car radio applications.

Thanks to the fully complementary PNP/NPN output configuration the TDA7386 allows a rail to rail output voltage swing with no need of bootstrap capacitors. The extremely reduced components count allows very compact sets.



April 1997

This is preliminary information on a new product now in development. Details are subject to change without notice.

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	Operating Supply Voltage	18	V
V _{CC (DC)}	DC Supply Voltage	28	V
V _{CC (pk)}	Peak Supply Voltage (t = 50ms)	50	V
IO	Output Peak Current: Repetitive (Duty Cycle 10% at f = 10Hz) Non Repetitive (t = 100μs)	4.5 5.5	A A
P _{tot}	Power dissipation, $(T_{case} = 70^{\circ}C)$	80	W
Tj	Junction Temperature	150	°C
T _{stg}	Storage Temperature	– 55 to 150	°C

PIN CONNECTION (Top view)



THERMAL DATA

Symbol	Parameter	Value	Unit
R _{th j-case}	Thermal Resistance Junction to Case Max.	1	°C/W



Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
l _{q1}	Quiescent Current	$R_L = \infty$		190	350	mA
V _{OS}	Output Offset Voltage	Play Mode			±80	mV
$\mathrm{dV}_{\mathrm{OS}}$	During mute ON/OFF output offset voltage				±80	mV
Gv	Voltage Gain		25	26	27	dB
dGv	Channel Gain Unbalance				±1	dB
Po	Output Power	$\begin{array}{l} V_S = 13.2V; \mbox{ THD} = 10\% \\ V_S = 13.2V; \mbox{ THD} = 0.8\% \\ V_S = 14,4V; \mbox{ THD} = 10\% \end{array}$		24 18 28		W W W
Po max	Max. Output Power (*)	EIAJ RULES ($V_S = 13.7V$)	37.5	40	-	W
		V _S = 14.4V		45		W
THD	Distortion	$P_o = 4W$		0.04	0.15	%
e _{No}	Output Noise	"A" Weighted Bw = 20Hz to 20KHz		50 70	70 100	μV μV
SVR	Supply Voltage Rejection	$f = 100Hz; V_r = 1Vrms$	50	75		dB
f _{ch}	High Cut-Off Frequency	$P_0 = 0.5W$	80	200		KHz
R _i	Input Impedance		70	100		KΩ
CT	Cross Talk	$ f = 1 KHz P_O = 4W \\ f = 10 KHz P_O = 4W $	60	70 60	- -	dB dB
I _{SB}	St-By Current Consumption	$V_{St-By} = 1.5V$			100	μA
I _{pin4}	St-by pin Current	VSt-By = 1.5V to 3.5V			±10	μA
V _{SB out}	St-By Out Threshold Voltage	(Amp: ON)	3.5			V
$V_{\text{SB in}}$	St-By in Threshold Voltage	(Amp: OFF)			1.5	V
A _M	Mute Attenuation	P _{Oref} = 4W	80	90		dB
V _{M out}	Mute Out Threshold Voltage	(Amp: Play)	3.5			V
V _{M in}	Mute In Threshold Voltage	(Amp: Mute)			1.5	V
V _{AM in}	V _S Automute Threshold	(Amp: Mute) Att ≥ 80dB; P _{Oref} = 4W (Amp: Play)			6.5	V
		Att < 0.1dB; P _O = 0.5W	_	7.6	8.5	V
I _{pin22}	Muting Pin Current	V _{MUTE} = 1.5V (Sourced Current)	5	11	20	μA
		$V_{MUTE} = 3.5V$	-5		20	μΑ

ELECTRICAL CHARACTERISTICS (V_S = 14.4V; f = 1KHz; R_g = 600 Ω ; R_L = 4 Ω ; T_{amb} = 25°C; Refer to the test and application diagram, unless otherwise specified.)

(*) Saturated square wave output.



TDA7386









Figure 2: P.C.B. and component layout of the figure 1 (1:1 scale)





Figure 3: Quiescent Current vs. Supply Voltage









Figure 4: Quiescent Output Voltage vs. Supply Voltage









SGS-THOMSON MICROELECTROMICS

57



6/9



Figure 9: Supply Voltage Rejection vs.

Figure 11: Output Noise vs. Source Resistance



APPLICATION HINTS (ref. to the circuit of fig. 1) <u>SVR</u>

Besides its contribution to the ripple rejection, the SVR capacitor governs the turn ON/OFF time sequence and, consequently, plays an essential role in the pop optimization during ON/OFF transients. To conveniently serve both needs, ITS MINIMUM RECOMMENDED VALUE IS 10µF.

INPUT STAGE

The TDA7386's inputs are ground-compatible and can stand very high input signals (± 8Vpk) without any performances degradation.

If the standard value for the input capacitors $(0.1\mu F)$ is adopted, the low frequency cut-off will amount to 16 Hz.

STAND-BY AND MUTING

STAND-BY and MUTING facilities are both





Figure 12: Power Dissipation & Efficiency vs. Output Power



CMOS-COMPATIBLE. If unused, a straight connection to Vs of their respective pins would be admissible. Conventional/low-power transistors can be employed to drive muting and stand-by pins in absence of true CMOS ports or microprocessors.

R-C cells have always to be used in order to smooth down the transitions for preventing any audible transient noises.

Since a DC current of about 10 uA normally flows out of pin 22, the maximum allowable muting-series resistance (R_2) is 70K Ω , which is sufficiently high to permit a muting capacitor reasonably small (about 1µF).

If R₂ is higher than recommended, the involved risk will be that the voltage at pin 22 may rise to above the 1.5 V threshold voltage and the device will consequently fail to turn OFF when the mute line is brought down.

About the stand-by, the time constant to be assigned in order to obtain a virtually pop-free transition has to be slower than 2.5V/ms.



TDA7386

DIM.	mm		inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А			5.00			0.20
E		0.38			0.015	
F		0.50			0.020	
G	0.80	1.00	1.20		0.040	
G1		24.00			0.944	
H1	28.90	29.23	29.30	1.137	1.15	1.153
H3		17.00			0.67	
H4		0.80			0.031	
L	6.21	6.36	6.51	0.24	0.25	0.256
L3	15.35	15.50	15.65	0.60	0.61	0.616

FLEXIWATT25 PACKAGE MECHANICAL DATA



SGS-THOMSON MICROELECTRONICS

8/9

Information furnished is believed to be accurate and reliable. However, SGS-THOMSON Microelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of SGS-THOMSON Microelectronics. Specification mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. SGS-THOMSON Microelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of SGS-THOMSON Microelectronics.

© 1997 SGS-THOMSON Microelectronics - Printed in Italy - All Rights Reserved

SGS-THOMSON Microelectronics GROUP OF COMPANIES

Australia - Brazil - Canada - China - France - Germany - Hong Kong - Italy - Japan - Korea - Malaysia - Malta - Morocco - The Netherlands -Singapore - Spain - Sweden - Switzerland - Taiwan - Thailand - United Kingdom - U.S.A.

